DRA4144W

Silicon PNP epitaxial planar type

For digital circuits Complementary to DRC4144W DRA2144W in NS through hole type package

Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- Contributes to miniaturization of sets, mount area reduction
- Eco-friendly Halogen-free package

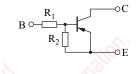
Packaging

DRA4144W0A Radial type: 5000 pcs / carton

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	-50	V	
Collector-emitter voltage (Base open)	V _{CEO}	-50	V	
Collector current	I _C	-100	mA	
Total power dissipation	P _T	300	mW	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	O°C	

- Package
- Code
- NS-B2-B-B
 - Package dimension clicks here. \rightarrow
- Pin Name
- 1: Emitter
- 2: Collector
- 3: Base
- Marking Symbol: LK
- Internal Connection



Resistance value	R ₁	47	kΩ	
	R ₂	22	kΩ	

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min) Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = -10 \ \mu {\rm A}, I_{\rm E} = 0$	-50			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$	-50			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{\rm CB} = -50$ V, $I_{\rm E} = 0$			- 0.1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{\rm CE} = -50$ V, $I_{\rm B} = 0$			- 0.5	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{\rm EB} = -6$ V, $I_{\rm C} = 0$			- 0.2	mA
Forward current transfer ratio	\mathbf{h}_{FE}	$V_{\rm CE} = -10$ V, $I_{\rm C} = -5$ mA	60			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = -10$ mA, $I_{\rm B} = -0.5$ mA			-0.25	V
Input voltage (ON)	V _{I(on)}	$V_{\rm CE} = -0.2$ V, $I_{\rm C} = -5$ mA	-4.4			V
Input voltage (OFF)	V _{I(off)}	$V_{CE} = -5 \text{ V}, I_C = -100 \mu\text{A}$			-1.2	V
Input resistance	R ₁		-30%	47	+30%	kΩ
Resistance ratio	R_1/R_2		1.70	2.14	2.60	_

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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